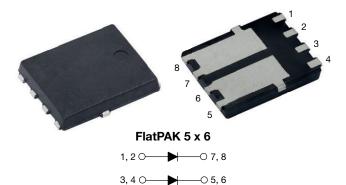
### Vishay Semiconductors



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# Hyperfast Rectifier, 2 x 4 A FRED Pt®



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 4 A					
V <sub>R</sub>	200 V					
V <sub>F</sub> at I <sub>F</sub>	0.7 V					
t <sub>rr (typ.)</sub>	25 ns					
T <sub>J</sub> max.	175 °C					
Package	FlatPAK 5 x 6					
Circuit configuration	Separated cathode					

#### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specific for output and snubber operation
- Low forward voltage drop
- · Low leakage current
- AEC-Q101 qualified
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260  $^\circ\mathrm{C}$
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, piezo-injection, as high frequency rectifiers, and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

#### **MECHANICAL DATA**

**Case:** FlatPAK 5 x 6 Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V			
Average rectified forward current	per device	1	T <sub>Solderpad</sub> = 170 °C, DC	- 8	А			
Average rectilied forward current	per device	I <sub>F(AV)</sub>	T <sub>Solderpad</sub> = 169 °C, D = 0.5					
Non-repetitive peak surge current	per device		T <sub>.1</sub> = 25 °C, 10 ms sinusoidal pulse	173	A			
Non-repetitive peak surge current	per diode	IFSM	1J = 23 °C, 10 mis sinusoidai puise	87				
Operating junction and storage temp	eratures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	200	-	-				
Forward valtage, per diade	V <sub>F</sub>	$I_F = 4 A$	-	0.87	0.96	V			
Forward voltage, per diode		I <sub>F</sub> = 4 A, T <sub>J</sub> = 150 °C	-	0.7	0.78				
Reverse leakage current, per diode	1	$V_{R} = V_{R}$ rated	-	-	2				
neverse leakage current, per diode	IR	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	7	80	μA			
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	19	-	pF			

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_{\rm F} = 1.0 \text{ A}, \text{ d}I_{\rm F}/\text{dt} =$	= 50 A/µs, V <sub>R</sub> = 30 V	-	20	-			
Bowerse receiver time	+	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	-	25			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	17	-	ns		
		T <sub>J</sub> = 125 °C		-	29	-			
Deels receivers ourrent		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 4 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 160 V	-	2.1	-	А		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	4	-	A		
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	18	-	nC		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	60	-	nc		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Thermal resistance, junction to ambient, per diode	R <sub>thJA</sub> <sup>(1)(2)</sup>		-	89	103	°C/W		
Thermal resistance, junction to mount, per diode	R <sub>thJM</sub> <sup>(3)</sup>		-	1.8	2.1	0/10		

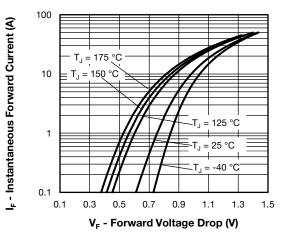
#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{thJA}$ 

 $^{(2)}$  Free air, mounted or recommended copper pad area; thermal resistance R<sub>thJA</sub> - junction to ambient

<sup>(3)</sup> Mounted on infinite heatsink

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Fig. 1 - Typical Forward Voltage Drop Characteristics

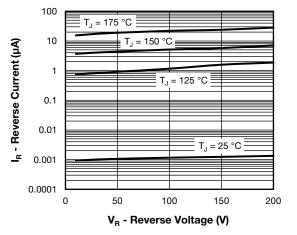


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

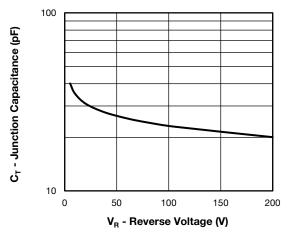


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

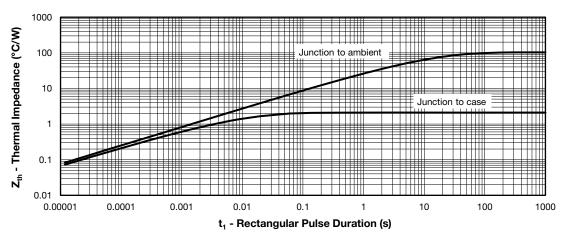
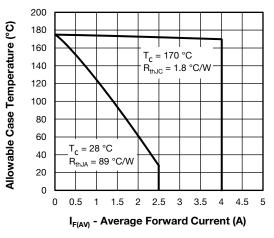


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

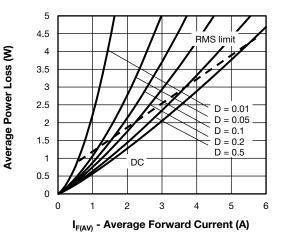


Fig. 6 - Forward Power Loss Characteristics

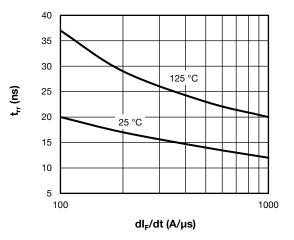


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

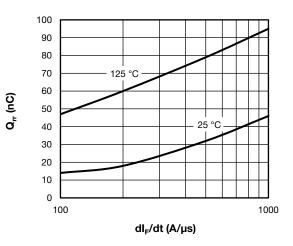


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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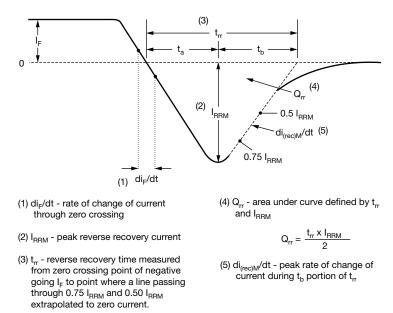


Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

**VISHAY** 

Device code	VS-	8	D	к	Н	02	Н	М3
		2	3	4	5	6	7	8
	브		-	nicondu	•	oduct		
				ng (8 = iguratio	-			
	4			ted cath ≺ packa				
	H		cess typ	•	ye			
		H =	hyper f	ast reco	very			
	6	- Vol	tage coo	de (02 =	200 V)			
	7	- H=	AEC-Q	101 qua	lified			
	8	- M3	= halog	en-free,	RoHS-0	complia	nt, and	termina

ORDERING INFORMATION (example)								
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY PACKAGING								
VS-8DKH02HM3/H	0.10	Н	1500	7"diameter plastic tape and reel				
VS-8DKH02HM3/I	0.10	I	6000	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96056					
Part marking information	www.vishay.com/doc?96059					
Packaging information	www.vishay.com/doc?88869					

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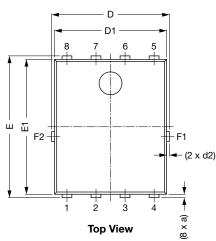


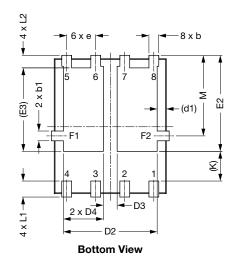
## **Outline Dimensions**

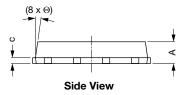
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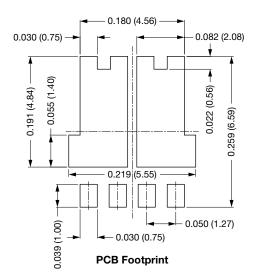
# FlatPAK 5 x 6 (Dual)

#### **DIMENSIONS** in inches (millimeters)









DIM		INCHES		MILLIMETERS				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.035	0.039	0.043	0.89	0.99	1.09		
(a)	-	0.006	-	-	0.15	-		
b	0.013	0.017	0.020	0.32	0.43	0.52		
b1	0.013	0.017	0.020	0.32	0.43	0.52		
С	0.008	-	0.014	0.20	-	0.35		
D	0.197	0.203	0.209	5.00	5.15	5.30		
D1	0.189	0.193	0.197	4.80	4.90	5.00		
D2	0.154	0.161	0.169	3.90	4.10	4.30		
D3	0.020	0.024	0.031	0.50	0.60	0.80		
D4	0.063	0.069	0.075	1.60	1.75	1.90		
(d1)	-	0.016	-	-	0.40	-		
(d2)	-	0.005	-	-	0.125	-		
E	0.238	0.244	0.250	6.05	6.20	6.35		

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# **Outline Dimensions**

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DIM.		INCHES			MILLIMETERS	RS	
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
E1	0.228	0.232	0.236	5.80	5.90	6.00	
E2	0.157	0.165	0.173	4.00	4.20	4.40	
(E3)	-	0.144	-	-	3.65	-	
е		0.050 BSC		1.27 BSC			
(K)	0.039	-	-	1.00	-	-	
L1	0.019	-	0.043	0.48	-	1.10	
L2	0.012	-	0.031	0.30	-	0.80	
М	0.128	0.138	0.148	3.25	3.50	3.75	
Θ	0°	-	10°	0°	-	10°	

Notes

• Dimensioning and tolerancing per ASME Y14.5-2009

• Dimensions D1 and E1 do not include mold flash or gate burrs

• Dimension (XX) means reference only



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